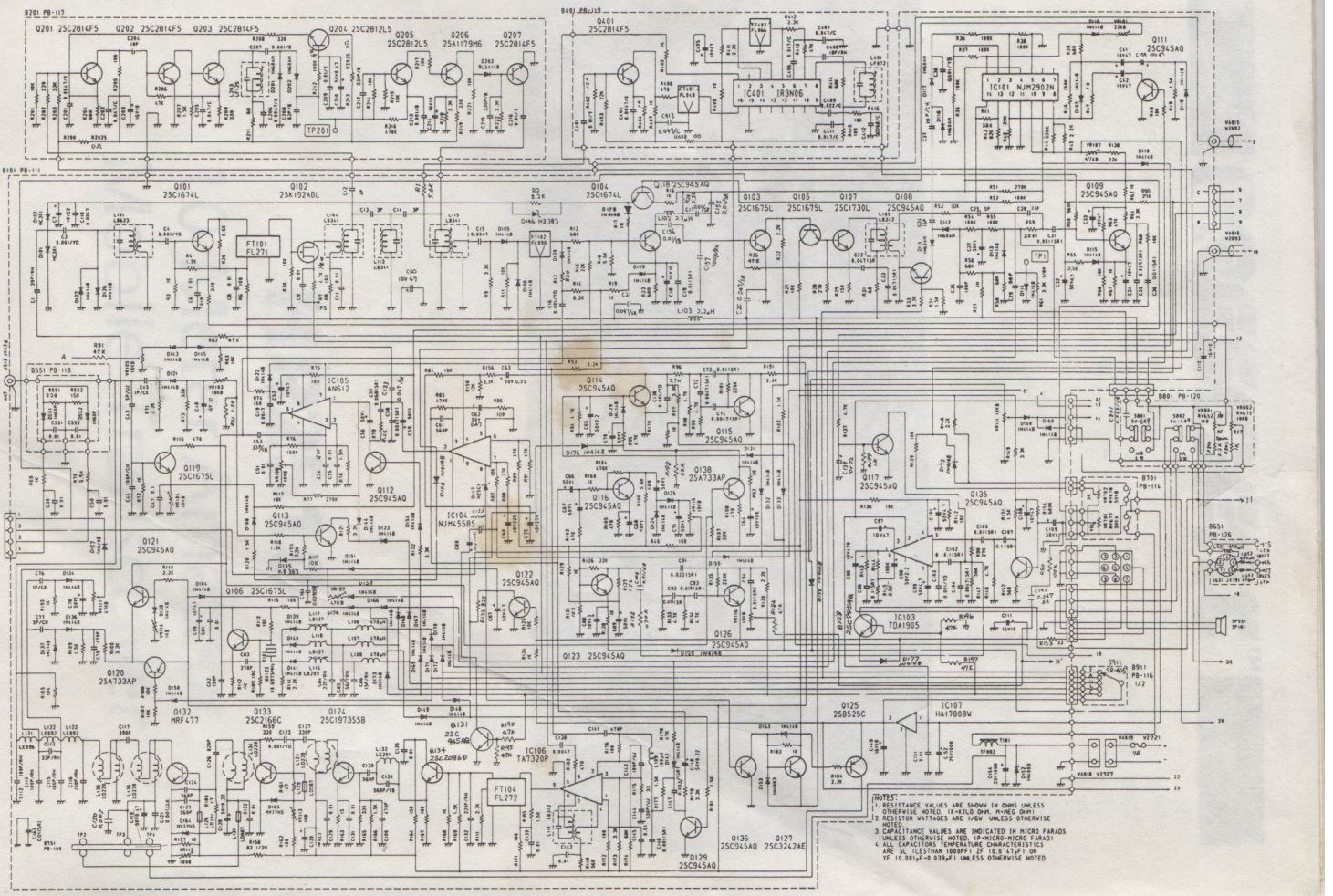
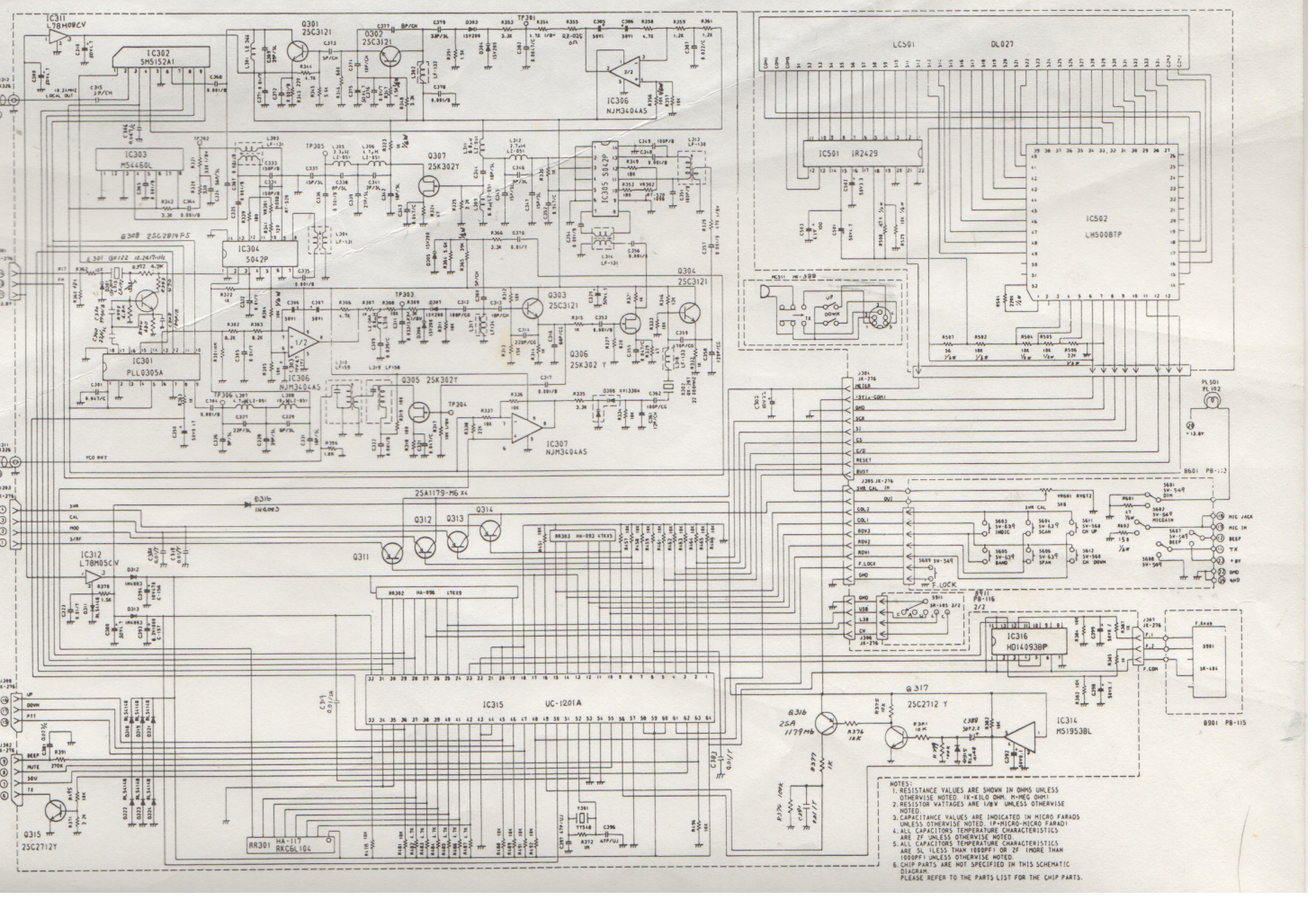

NOTES:
1. RESISTANCE VALUES ARE SHOWN IN OHMS UNLESS OTHERWISE NOTED. (K=KILO OHM, M=MEG OHM)
2. RESISTOR WATTAGES ARE 1/8W UNLESS OTHERWISE NOTED.
3. CAPACITANCE VALUES ARE INDICATED IN MICRO FARADS UNLESS OTHERWISE NOTED. (P=MICRO-MICRO FARAD)
4. ALL CAPACITORS TEMPERATURE CHARACTERISTICS ARE SL (LESS THAN 1000PF) 2F (8.0 47pF) OR YF (0.001pF~0.039pF) UNLESS OTHERWISE NOTED.


NOTES:
1. RESISTANCE VALUES ARE SHOWN IN OHMS UNLESS OTHERWISE NOTED. (K=KILO OHM, M=MEG OHM)
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4. ALL CAPACITORS TEMPERATURE CHARACTERISTICS ARE 2F UNLESS OTHERWISE NOTED.
5. ALL CAPACITORS TEMPERATURE CHARACTERISTICS ARE SL (LESS THAN 1000PF) OR 2F (MORE THAN 1000PF) UNLESS OTHERWISE NOTED.
6. CHIP PARTS ARE NOT SPECIFIED IN THIS SCHEMATIC DIAGRAM. PLEASE REFER TO THE PARTS LIST FOR THE CHIP PARTS.